

型名	社名	用途	構造	最大定格 (T _a = 25°C)					電 気 的 特 性 (T _a = 25°C)											外形	備考					
				V _{CEO} (V)	V _{EB0} (V)	I _C (mA)	P _C (mW)	T _J (°C)	I _{CEO} 最大値 (μA)	V _{CE(V)}	直流又はパルス h _{FE} I _C (mA)	バイアス V _{CB(V)}		I _E (mA)	h _{je} h _{je} *	h _{ie} h _{ie} * (Ω)	h _{re} h _{re} * (×10 ⁻⁴)	h _{oe} h _{oe} * (μU)	f _{βB} f _T * (Mc)			C _{ob} (pF)	r _{bb} h _{ie(real)} * (Ω)			
2SC1841	日電	AF	Si.E	120	5	50	500	125	0.05	120	600	6	1	6	-1							110*	1.6		138	
" 1842	"	RF.LN	"	40		100	250	125	0.1	40	500	6	1	6	-1	NF=1.2dB (6V, 1mA, 100Hz)					120*	3.5	50*	138		
" 1843	"	"	"	60		100	250	125	0.1	60	400	6	1	6	-1	NF=0.8dB (6V, 1mA, 100Hz)					110*	3.5	50*	138		
" 1844	"	AF.LN	Si.E	60	5	100	500	125	0.05	60	400	6	1	6	-1	V _{VO} < 45mV (5V, 1mA, R _C =100kΩ, A _v =80dB)					100*	4.8		138	2SA991 とコンパリ	
" 1845	"	"	"	120	5	50	500	125	0.05	120	600	6	1	6	-1	V _{VO} < 40mV (5V, 1mA, R _C =100kΩ, A _v =80dB)					110*	1.6		138	2SA992 とコンパリ	
" 1846	松下	PA	Si.EP	45	5	1A	1.2W	150	0.1	20	160	10	500	10	-50							200*	15	3.5k*	222	2SA885 とコンパリ
" 1847	"	"	"	50	5	1.5A	1.2W	150	1	20	120	5	1A	5	-500							150*	50	3.3k*	222	2SA886 とコンパリ
" 1848	"	"	"	70	5	2A	1.2W	150	1	40	130	5	1A	5	-500							150*	50	3k*	161	2SA887 とコンパリ
" 1849	"	RF.AF	"	30	5	100	350	135	1	10	250	10	2	10	-2	250	5k	0.4	20		150*	3.5	70	138D		
" 1850	"	"	"	60	5	100	350	135	1	10	250	10	2	10	-2	250	5k	0.4	20		150*	3.5	70	138D		
" 1851	"	PA	"	30	5	500	625	135	0.1	20	160	10	150	10	-50						200*	6	3.5k*	138D	2SA890 とコンパリ	
" 1852	"	"	"	60	5	500	625	135	0.1	20	160	10	150	10	-50						200*	6	3.5k*	138D	2SA891 とコンパリ	
" 1853	"	RF.Conv.Mix Osc	"	30	5	30	250	125	1	10	250	10	1	10	-1						230*	1.3	35	138		
" 1854	"	RF.AF	"	30	5	50	250	125	1	10	200	5	2	5	-2	220	5k	0.4	20		150*	2.2	70	138		
" 1855	日立	RF	Si.Pa	20	3	20	250	125	0.1	20	20~200	10	2	10	-2	G _{re} = 28dB V _{CC} = 12V, I _C = 4mA, f = 45MHz				550*	C _{re} 0.35		138C			
" 1856	"	"	"	20	3	20	250	125	0.1	20	20~200	10	2	10	-2	G _{re} = 22dB V _{CC} = 12V, I _C = 2mA, f = 200MHz				550*	C _{re} 0.35		138C			
" 1857	"	"	Si.T	300	5	100	800	150	1	250	100	20	20	20	-20						80*	3	20*	84B		
" 1858																										
" 1859	ソニー	RF	Si.E Pa.Me	25	5	1.5A	500	120	0.2	25	180	2	100	10	-10						140*	15	C _e r _{bb} 250pS	138		
" 1860	日電	SW	Si.E	150	7	2A	800	150	1	100	70	5	100			t _{on} < 0.5μS, t _f < 0.5μS t _{off} < 1μS							84B			
" 1861	"	"	"	300	7	2A	800	150	10	250	60	5	100			t _{on} < 1μS, t _f < 1μS t _{off} < 2μS							84B			
" 1862	"	"	Si.T	450	7	2A	800	150	10	400	40	5	100			t _{on} < 1μS, t _f < 1μS t _{off} < 2.5μS							84B			
" 1863	"	"	Si.EMe	150	7	7A	40W (T _c =25°C)	150	100	100	>20	5	3A			t _{on} < 1μS, t _f < 1μS t _{off} < 2μS							134			
" 1864	"	"	"	300	7	7A	40W (T _c =25°C)	150	100	250	>20	5	3A			t _{on} < 1μS, t _f < 1μS t _{off} < 2.5μS							134			
" 1865	"	"	Si.TMe	450	7	7A	40W (T _c =25°C)	150	100	400	>15	5	3A			t _{on} < 1μS, t _f < 1μS t _{off} < 2μS							134			
" 1866	"	"	"	150	7	7A	80W (T _c =25°C)	150	100	100	>20	5	3A			t _{on} < 1μS, t _f < 1μS t _{off} < 2μS							102			
" 1867	"	"	Si.EMe	300	7	7A	80W (T _c =25°C)	150	100	250	>20	5	3A			t _{on} < 1μS, t _f < 1μS t _{off} < 2μS							102			
" 1868	"	"	Si.TMe	450	7	7A	80W (T _c =25°C)	150	100	400	>15	5	3A			t _{on} < 1μS, t _f < 1μS t _{off} < 2μS							102			
" 1869	"	"	"	150	7	10A	100W (T _c =25°C)	150	100	100	>20	5	5A			t _{on} < 1μS, t _f < 1μS t _{off} < 2μS							102			
" 1870	"	"	"	300		10A	100W (T _c =25°C)	150	100	250	>20	5	5A			t _{on} < 1μS, t _f < 1μS t _{off} < 2μS							102			